



100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C	
100V	8.6mΩ @ V _{GS} = 10V	98.4A	

Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize $R_{DS(ON)}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switch.

Applications

- Motor Control
- DC-DC Converters
- Power Management

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

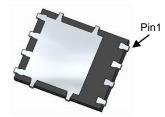
Mechanical Data

- Case: PowerDI[®] 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

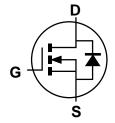
PowerDI5060-8



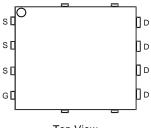
Top View



Bottom View



Internal Schematic



Top View Pin Configuration

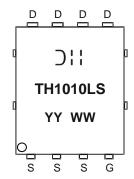
Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH10H010LPS-13	PowerDI5060-8	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



| | = Manufacturer's Marking TH1010LS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17= 2017) WW = Week Code (01 to 53)

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Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	100	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Proin Current (1/ 401/)	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	10.8 7.6	А
Continuous Drain Current (V _{GS} = 10V)	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	98.4 69.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	250	Α		
Maximum Continuous Body Diode Forward Current	Is	95	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			I _{SM}	250	Α
Avalanche Current, L=0.3mH			I _{AS}	15	Α
Avalanche Energy, L=0.3mH			Eas	33.7	mJ

Thermal Characteristics

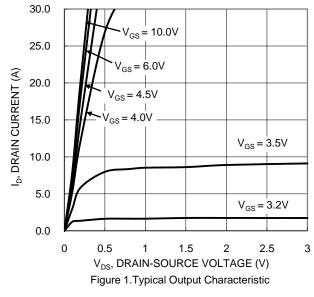
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	99	°C/W
Total Power Dissipation	T _C = +25°C	P _D	125	W
Thermal Resistance, Junction to Case	R _{0JC}	1.2	°C/W	
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +175	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	1	1	٧	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	-	1	μΑ	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(TH)}	1.4	1.9	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	6.9	8.6		$V_{GS} = 10V, I_D = 13A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	7.5	12	mΩ	$V_{GS} = 6V, I_D = 13A$	
		_	10	20	1	$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	V_{SD}	_	0.8	1.3	V	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	2592	_		V _{DS} = 50V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	792	1	pF		
Reverse Transfer Capacitance	Crss	_	45				
Gate Resistance	R_g	_	2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	53.7	_		V 50V L 40A	
Gate-Source Charge	Q _{gs}	_	10.6	_	nC	$V_{DD} = 50V, I_D = 13A,$	
Gate-Drain Charge	Q _{gd}	_	8.2	_		V _{GS} = 10V	
Turn-On Delay Time	t _{D(ON)}	_	11.6	_			
Turn-On Rise Time	t _R	_	14.1	_		$V_{DD} = 50V, V_{GS} = 10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	42.9	_	ns	$I_D = 13A$, $R_g = 6\Omega$	
Turn-Off Fall Time	t _F	_	22	_			
Reverse Recovery Time	t _{RR}	_	49.8	_	ns	1 404 31/31 4004/	
Reverse Recovery Charge	Q _{RR}	_	85.1	_	nC	I _F = 13A, di/dt = 100A/μs	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing. Notes:





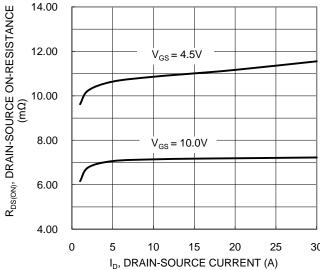


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

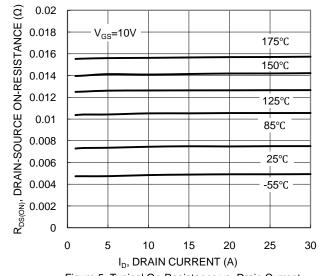
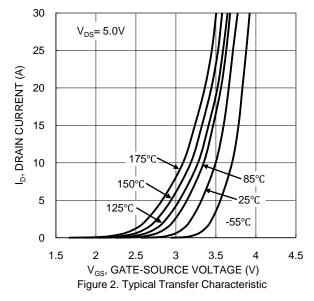
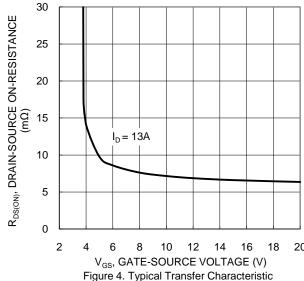


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





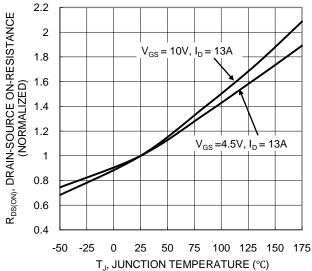


Figure 6. On-Resistance Variation with Temperature



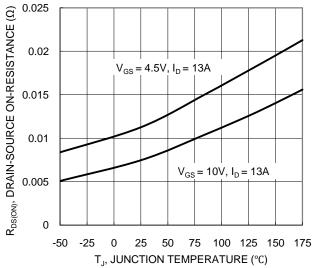


Figure 7. On-Resistance Variation with Temperature

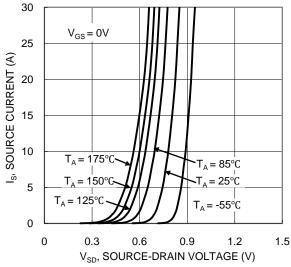
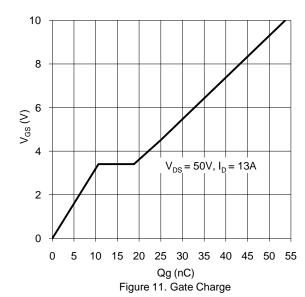


Figure 9. Diode Forward Voltage vs. Current



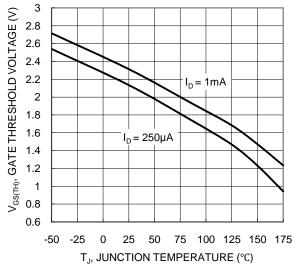
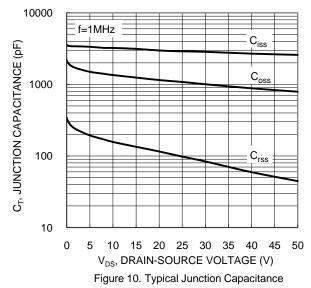


Figure 8. Gate Threshold Variation vs. Junction Temperature



1000 $R_{DS(ON)}$ LIMITED 100 l_D, DRAIN CURRENT (A) T_{J(MAX)}=150°C T_C=25°C =10ms P_w=100ms Single Pulse DUT on infinite heatsink V_{GS}=10V 0.01 0.1 1000 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area



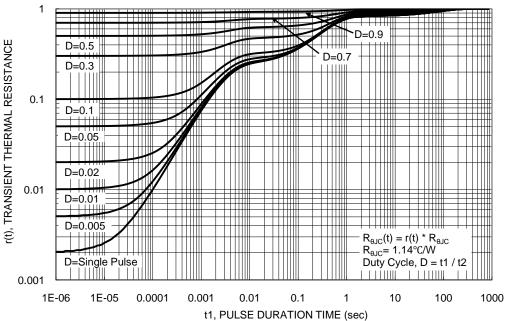


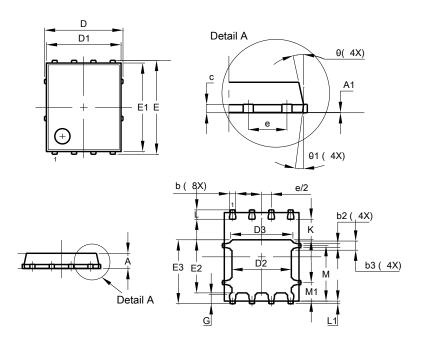
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

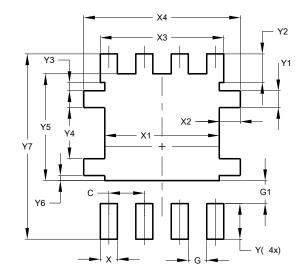


PowerDI5060-8						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D	į	5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90 4.30 4.10					
Е	6.15 BSC					
E1	5.60	5.60 6.00				
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
e G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
M	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
θ	10°	12º	11º			
θ1	6º	8º	7º			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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DMTH10H010LPS
Document number: DS39907 Rev. 3 - 2

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